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Investigation of experimental design methodology to elaborate NiFe₂O₄ thin film by eco-friendly method

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Highlights

- Experimental design methodology has been applied to investigate the influence of the principal experimental parameters on saturation magnetization.
- Optimal condition of NiFe₂O₄ thin film has been investigated by Doehlert matrix.
- The obtained NiFe₂O₄ thin film was elaborated by chemical bath deposition.
- Electrochemical properties of NiFe₂O₄ thin film have been investigated in 1M NaOH aqueous electrolyte.

Abstract

The experimental design methodology has been applied to determine the influence of the experimental parameters and their interaction on saturation magnetization (M_s) of thin films. The saturation magnetization (M_s) is very influenced by the deposition and annealing temperature which is proved by Rechtschaffner design. The optimal condition of the NiFe₂O₄ thin film has been predict by Doehlert matrix. The prepared NiFe₂O₄ thin film under optimal condition synthesized by a green chemistry method, was characterized by XRD, FTIR and Raman spectrometer for structural and phase identification. The flower-like structure of the NiFe₂O₄ thin film has been revealed by SEM analysis. The ferrimagnetic behavior of the NiFe₂O₄ elaborated at the optimal conditions has been determined by VSM measurement. The measured saturation magnetization (0.49 T) agrees with M_s (0.48 T) predict by Rechtschaffner design. The double-layer capacitance (EDLC) of NiFe₂O₄ has been investigated by cyclic voltammetry which show a semi-rectangular shape in the negative and positive potential

and the electrochemical impedance spectroscopy confirm the resistance behavior of the NiFe₂O₄ electrode.

Keywords: NiFe₂O₄ thin film, Chemical bath deposition (CBD), Rechtschaffner design, Magnetic properties, Electrochemical properties.

1. Introduction

The inverse Spinel ferrites with Fd $\bar{3}m$ space group are a class of materials with general structure of AFe₂O₄ (A corresponds to Mn⁺², Fe²⁺, Co²⁺, Ni²⁺, etc...) where the divalent ions switch with half of trivalent ions between tetrahedral and octahedral sites [1]. The ferrites are most prepared in bulk for this many researchers developed ferrites in nanoparticles or thin films [2, 3]. However, thin film materials, plays critical role in the development of ferrite materials with great properties [4] and performance [5]. In fact, the synthesis conditions affect mostly the materials characteristics such as crystallinity, homogeneity, porosity, roughness [6].

The ferrite thin films are attractive due to their remarkable ferromagnetic properties as unique magnetic structure, high saturation magnetization (M_s), high magnetic anisotropy, low magnetic coercivity, and remarkable electrochemical and thermal stability, which render them suitable for many applications, such as electronics devices [7], magnetic information storage [8], microwave absorption [9], photocatalysis [10], supercapacitors [11], lithium ion batteries [12], electrochemical sensor [13], gas sensors [14], fuel cells [15], etc.

Thus, ferrite thin films were successfully synthesis by several techniques which can be categorized into physical and chemical methods. The physical methods which include pulsed laser deposition (PLD) [16], molecular beam epitaxy (MBE) [17] and RF magnetron sputtering [18], however the chemical methods consist electrodeposition [19], sol-gel [20], spin-spraying [21], spin coating [22], dip-coating [23], successive ionic layer adsorption and reaction (SILAR) [24], reflux [25], chemical vapor deposition (CVD) [26] and chemical bath deposition (CBD) [27]. Otherwise, the chemical bath deposition (CBD) has many advantageous, the low-cost, the simply, the rapidity and the ecology of this technique. Also, the CBD method can offer the control of the preparative parameters such as precursor concentration, deposition time, bath temperature, pH, etc. However, the possibility to control thus parameters allowed us to use experimental design methodology.

The experimental design [28] is become very useful to perform the optimization of the variables and preliminary studies of experimental parameters such as the temperature of

deposition (T_d), the time of deposition (t_d), the concentration, the pH, the annealing temperature (T_R) etc. Traditional univariate approaches are performed by varying each experimental parameter independently of the others, while Rechtschaffner designs represents the best solution to perform the optimization of many variables. However, the motivation behind the use of Rechtschaffner and Doehlert designs [29] in the current study is mainly due to its minimal number of experimental runs that does not compromise with the quality of the achieved results and a clear identification between different factor interactions.

In this study, we use the experimental design methodology to investigate the influence of the principal experimental parameters such as temperature deposition (T_d), time deposition (t_d), $R' = [\text{Fe}]/[\text{OH}^-]$ parameter, pH, annealing temperature (T_R) and annealing time (t_R) on the saturation magnetization (M_s) of NiFe_2O_4 thin film. The optimal conditions for the deposition of NiFe_2O_4 thin film has been studied using Doehlert matrix. The obtained thin film into the optimal conditions elaborate by chemical bath deposition has been examined by X-ray diffraction technique, Raman , FTIR, scanning electron microscopy, vibrating sample magnetometer, cyclovoltammetry and Electrochemical Impedance Spectroscopy to study the structural, spectroscopic, morphological, magnetic and electrochemical properties respectively.

2. Experimental details

All the chemical precursors used in this work were purchased from Aldrich and used without further purification.

2.1. Preparation of optimal NiFe_2O_4 thin film

The optimal NiFe_2O_4 thin film has been deposited by low-cost chemical bath deposition (CBD) in stainless steel (SS) substrates. The stainless steel (SS) substrate has been polished by polish paper and cleaned with deionized water to remove unwanted oxides formed on the surface. The cleaned stainless steel (SS) substrate was immersed in the basic solution of iron chloride and nickel chloride under constant stirring for 2 h. Then, the film has been taken out from the bath and washed with de-ionized water to remove the excess of particles and finally, the film has been annealed in oven.

2.2. Characterization of optimal NiFe_2O_4 thin film

The NEMROD Software program [30] has been used to determine the optimal condition of the NiFe_2O_4 thin film. The structure of the NiFe_2O_4 thin film has been confirmed by X-ray diffraction technique at room temperature with a scanning range of $2\theta = 20 - 90^\circ$ using a D8

advanced X-ray diffractometer ($\lambda(\text{Cu-K}\alpha) = 1.5406 \text{ \AA}$). Fourier transform infrared (FTIR) and Raman were utilized to identify chemical bonds of NiFe_2O_4 thin film in the range of 200-4000 cm^{-1} . The surface morphology of the film has been studied by Merlin scanning electron microscopy (SEM) equipped with Silicon Drift Detector (SDD)-X-Max 50 from Oxford Instrument. The magnetic behavior of the prepared thin film has been recorded by Vibrating Sample Magnetometer (VSM) at room temperature with maximum applied field of $\pm 15 \text{ kA/m}$. The cyclovoltammetry (CV), the electrochemical impedance spectroscopy (EIS) and the tafel polarization have been performed at room temperature using PGZ-402 potentiostat with a three-electrode cell. The CV, the measurements were recorded in a solution of 1 M NaOH in the potential range of -0.5 to 0.5 V at the scan rate of 100 mVs^{-1} and the EIS measurements were carried out in open circuit potential in the frequency range of 1 Hz -100 KHz.

Results and discussion

2.3. Influence of the operating parameters on saturation magnetization (M_s) of NiFe_2O_4 thin film using Rechtschaffner design

In order to evaluate the influence of operating parameters on saturation magnetization (M_s) of the NiFe_2O_4 thin films six main parameters (factors) were chosen: deposition temperature (U_1), deposition time (U_2), concentration ratio $R' = [\text{Fe}]/[\text{OH}^-]$ (U_3), pH (U_4), annealing temperature (U_5) and annealing time (U_6). To determine the influence of these six factors and their interaction on saturation magnetization (M_s) of thin films a two-level full factorial design 2^{k-p} was used. In these types of designs, variables (k) are set at two levels (minimum) and (maximum) normalized as (-1) and (+1). The linear polynomial model of the experimental response associated to (2^{6-1}) factorial design (for 6 variables) was represented by the following equation:

$$Y = b_0 + b_1X_1 + b_2X_2 + b_3X_3 + b_4X_4 + b_5X_5 + b_6X_6 + b_{12}X_1X_2 + b_{13}X_1X_3 + b_{23}X_2X_3 + b_{14}X_1X_4 + b_{24}X_2X_4 + b_{34}X_3X_4 + b_{15}X_1X_5 + b_{25}X_2X_5 + b_{35}X_3X_5 + b_{45}X_4X_5 + b_{16}X_1X_6 + b_{26}X_2X_6 + b_{36}X_3X_6 + b_{46}X_4X_6 + b_{56}X_5X_6 \quad (1)$$

Were:

Y: experimental response (saturation magnetization (M_s))

X_i : coded variable (-1 or +1)

b_i : estimation of the principal effect of the factor i for the response Y

b_{ij} : estimation of interaction effect between factor i and j for the response Y .

Table 1. Experimental domain investigated for NiFe₂O₄ thin films

Coded variables (X _i)	Factors (U _i)	Unit	Experimental field	
			Lower limit	Upper limit
X ₁	U ₁ : deposition temperature (T _d)	°C	40	70
X ₂	U ₂ : deposition time (t _d)	min	60	180
X ₃	U ₃ : R' = [Fe]/[OH ⁻]	-	1.11	1.75
X ₄	U ₄ : pH	-	9	10
X ₅	U ₅ : annealing temperature (T _R)	°C	550	750
X ₆	U ₆ : annealing time (t _R)	h	4.30	6

The variables for the model was chosen referring to previous work [31]. The coefficients of the equation model were calculated in the experimental field are listed in **Table 1** and the results are represented in the **Table 2**. The coefficients of the linear polynomial model are calculated using only extremes by NEMROD Software program [30] which is represented in the following equation:

$$\begin{aligned}
Y = & 141.665 + 19.072 X_1 + 2.643 X_2 - 8.514 X_3 - 6.508 X_4 + 29.910 X_5 - 4.980 X_6 - 0.845 \\
& X_1X_2 - 5.155 X_1X_3 + 7.022 X_2X_3 - 9.656 X_1X_4 - 4.097 X_2X_4 - 0.934 X_3X_4 + 12.426 X_1X_5 + \\
& 3.482 X_2X_5 - 4.410 X_3X_5 - 7.203 X_4X_5 - 1.549 X_1X_6 - 3.442 X_2X_6 - 3.610 X_3X_6 - 7.673 X_4X_6 \\
& + 5.183 X_5X_6
\end{aligned} \quad (2)$$

Table 2. Experimental domain investigated for NiFe₂O₄ thin films

Experimental number	Experimental design						Experimental plan						Results Y (T)
	X ₁	X ₂	X ₃	X ₄	X ₅	X ₆	U ₁	U ₂	U ₃	U ₄	U ₅	U ₆	
1	-1	-1	-1	-1	-1	-1	40	60	1.11	9	550	4.30	0.112
2	-1	1	1	1	1	1	40	180	1.75	10	750	6	0.156
3	1	-1	1	1	1	1	70	60	1.75	10	750	6	0.18
4	1	1	-1	1	1	1	70	180	1.11	10	750	6	0.231
5	1	1	1	-1	1	1	70	180	1.75	9	750	6	0.282
6	1	1	1	1	-1	1	70	180	1.75	10	550	6	0.093
7	1	1	1	1	1	-1	70	180	1.75	10	750	4.30	0.232
8	1	1	-1	-1	-1	-1	70	180	1.11	9	550	4.30	0.169
9	1	-1	1	-1	-1	-1	70	60	1.75	9	550	4.30	0.143
10	1	-1	-1	1	-1	-1	70	60	1.11	10	550	4.30	0.181
11	1	-1	-1	-1	1	-1	70	60	1.11	9	750	4.30	0.286
12	1	-1	-1	-1	-1	1	70	60	1.11	9	550	6	0.180
13	-1	1	1	-1	-1	-1	40	180	1.75	9	550	4.30	0.145
14	-1	1	-1	1	-1	-1	40	180	1.11	10	550	4.30	0.151
15	-1	1	-1	-1	1	-1	40	180	1.11	9	750	4.30	0.182
16	-1	1	-1	-1	-1	1	40	180	1.11	9	550	6	0.111
17	-1	-1	1	1	-1	-1	40	60	1.75	10	550	4.30	0.162
18	-1	-1	1	-1	1	-1	40	60	1.75	9	750	4.30	0.138
19	-1	-1	1	-1	-1	1	40	60	1.75	9	550	6	0.106
20	-1	-1	-1	1	1	-1	40	60	1.11	10	750	4.30	0.185
21	-1	-1	-1	1	-1	1	40	60	1.11	10	550	6	0.112
22	-1	-1	-1	-1	1	1	40	60	1.11	9	750	6	0.156

As can be seen in **Fig.1a** the saturation magnetization is very influenced by the annealing temperature ($b_5 = 0.038$) as it has a positive response on the studied. In fact. the increasing of annealing temperature leads to increase the saturation magnetization. The second most significant factor is the temperature of deposition ($b_1 = 0.024$) which have positive effect on the studied response. There is a significant X_1X_5 interaction between the deposition and the annealing temperature ($b_{15} = 0.016$). Thus, the effect of the deposition temperature (X_1) depends on the annealing temperature (X_5) in the chosen range and vice versa which has a positive effect on the response. Note also that the effects of the other factors are very negligible.

The Pareto analysis gave more significant information to interpret the results of Rechtschaffner design. In fact, the advantage of this analysis is the calculation of the percentage effect of each factor on the response. The numerical values of this analysis are given by the following relation:

$$P_i = \left(\frac{b_i^2}{\sum b_i^2} \right) \times 100 \quad (3)$$

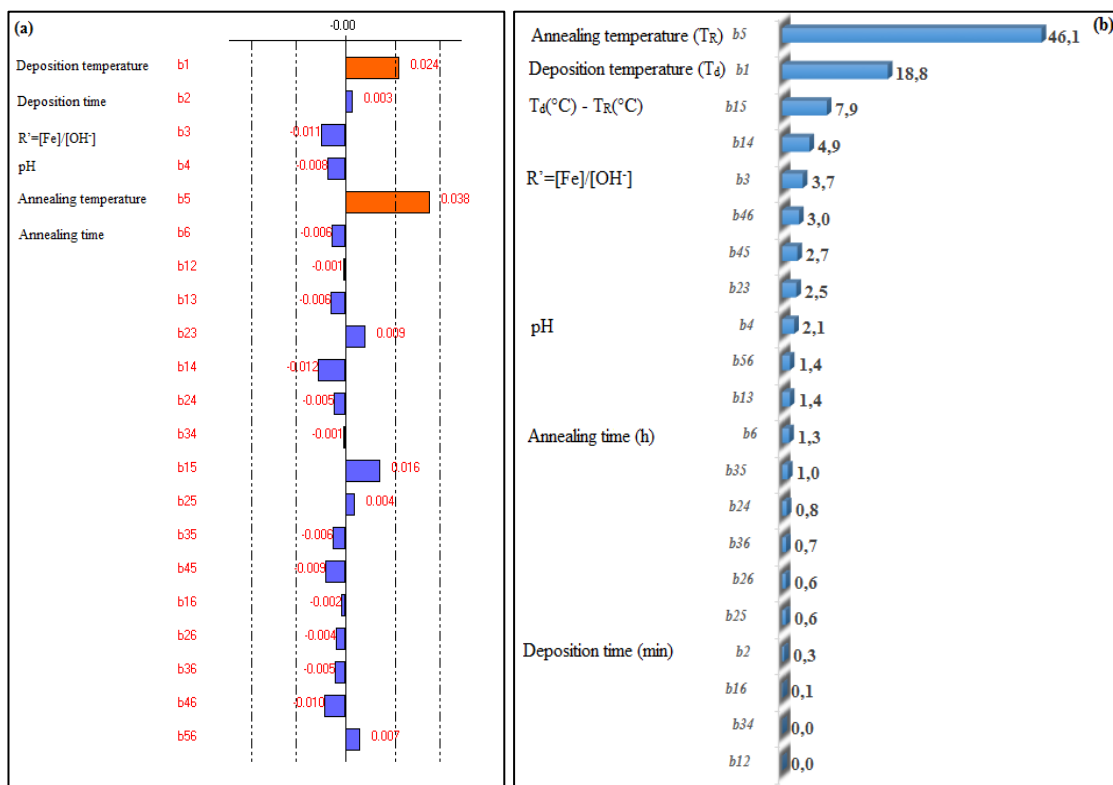


Fig. 1. (a) Graphical analysis of the effect of : deposition temperature, deposition time, R' , pH, annealing temperature and time, (b) Graphical Pareto analysis.

As can be seen in Pareto graphic analysis (**Fig.1b**), the annealing temperature is the most influential factors on the saturation magnetization with 46.1% contribution response. And the second parameters which influence on the saturation magnetization is the temperature of

deposition with total contribution of 18.7%. Furthermore, those factors have an important and meaningful positive interaction with a contribution of 64.8%. We can note also, that more than 72.7% of the response are bringing by the two factors and their interaction. However, the pH, R', deposition and annealing time and their interactions have a negligible effect with only 27.3% of the response.

2.4. Determination of the optimal condition of NiFe₂O₄ thin film using Doehlert design

In order to determine the optimal condition of NiFe₂O₄ thin film, the approach of Doehlert was applied after determination of the most influential parameters on saturation magnetization. The annealing and deposition temperature are the two factors determined in Rechtschaffner approach which will be investigated in the Doehlert study. The advantages of this approach are the ability to explore the whole of the experimental domain through a minimum number of experiments and the possibility to extend the domain by adding another factor.

Table 3. Experimental domain investigated for NiFe₂O₄ thin films

Coded variables (X _i)	Factors (U _i)	Unit	Experimental domain	
			Lower limit	Upper limit
X ₁	U ₁ : annealing temperature	°C	550	750
X ₂	U ₂ : deposition temperature	°C	40	70

The Doehlert approach is formed by uniformly distributed of the experimental points within the space filling of the coded variables (X_i). To compare the effects of those factors U_i cited previously in the experimental domain (**Table.3**), concerned coded variables were used. For calculation, the experimental value of the factors U₁ and U₂ were transformed into coded X₁ and X₂ using the following relation:

$$X_i = \frac{U_i - \bar{U}_i}{\Delta U_i} \quad (4)$$

where: X_i is the value taken by the coded variable i, U_i is the value taken by the factor i, \bar{U}_i is the value taken by the factor i in the center of the experimental field and ΔU_i is the range of variation of the factor i.

$$\bar{U}_i = \frac{(\text{upper limit of } (U_i) + \text{lower limit of } (U_i))}{2} \quad (5)$$

$$\Delta U_i = \frac{(\text{upper limit of } (U_i) - \text{lower limit of } (U_i))}{2\gamma_i} \quad (6)$$

The experimental response (saturation magnetization (M_s)) associated to the Doehlert approach can be described as following by a second-degree quadratic polynomial equation:

$$Y = b_0 + b_1X_1 + b_2X_2 + b_{11}X_1^2 + b_{22}X_2^2 + b_{12}X_1X_2 \quad (7)$$

Where:

Y: the experimental response (saturation magnetization (M_s));

b_0 : an independent term; b_i : the coefficients of the linear terms;

b_{ii} : the coefficients of the quadratic terms;

b_{ij} : the coefficients corresponding to the interaction term between the factor i and the factor j.

In addition, the calculation of the coefficients of this model was carried through the least squares method:

$$B = (X^T X)^{-1} \times X^T \times Y \quad (8)$$

where:

B: is the estimates coefficients vector;

X^T : is the transposed model matrix;

X: is the model matrix;

Y: is the measured response vector.

Using Doehlert approach, the number of experiments (N) required is given by the following relation: $N = k + k^2 + 1$, where k is the number of factors. As mentioned previously two factors influence on the saturation magnetization consequently, 7 different experiments were required. However, in order to validate this model, three replicated experiments at the center level were carried out. Doehlert matrix, experimental plan and results for the two selected factors were listed in **Table.4**.

Table 4. Experimental domain investigated for NiFe₂O₄ thin films

Experimental number	Experimental design		Experimental plan		Results Y(T)
	X ₁	X ₂	U ₁	U ₂	
1	1.0000	0.0000	750	55	0.427
2	-1.0000	0.0000	550	55	0.115
3	0.5000	0.8660	700	70	0.277
4	-0.5000	-0.8660	600	40	0.154
5	0.5000	-0.8660	700	40	0.453
6	-0.5000	0.8660	600	70	0.142
7	0.0000	0.0000	650	55	0.366
8	0.0000	0.0000	650	55	0.365
9	0.0000	0.0000	650	55	0.366

Based to these results, the coefficients of the polynomial model were calculated using NEMROD Software program mentioned above:

$$Y = 291,58 + 140,432 X_1 - 42,456 X_2 - 75,73 X_1^2 - 87,49 X_2^2 - 73,933 X_1 X_2 \quad (9)$$

The effects of the various factors: annealing temperature and deposition temperature were quantified respectively by b_1 and b_2 as well as their interactions b_{12} . **Figure.2** represents the effects of the various factors as well as their interactions. The annealing temperature has a positive effect ($b_1 = 140.43$) on M_s of the material, so any increase in the annealing temperature increases the value of M_s . The deposition temperature has a negative effect ($b_2 = -42.45$) on the value of M_s . It can be noted that the annealing temperature is the most influential factor on the response of M_s .

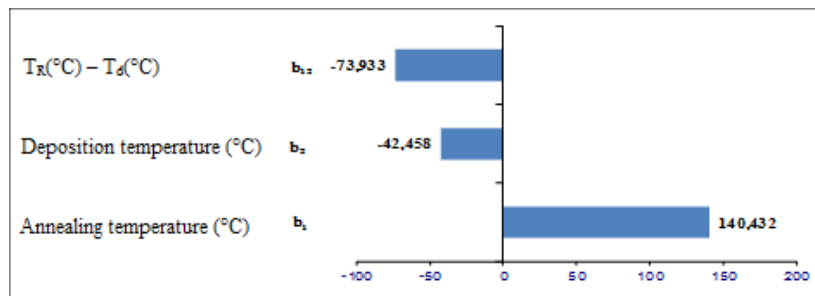


Fig. 2. Graphical analysis of the effect of deposition temperature and annealing temperature.

To confirm this result, we plotted the response surface curves in 3D as well as the isoreponse curves. **Figure.3** shows the isoreponse curve of M_s as a function of annealing temperature and deposition temperature and the 3D surface of M_s in the plane (T_R , T_d).

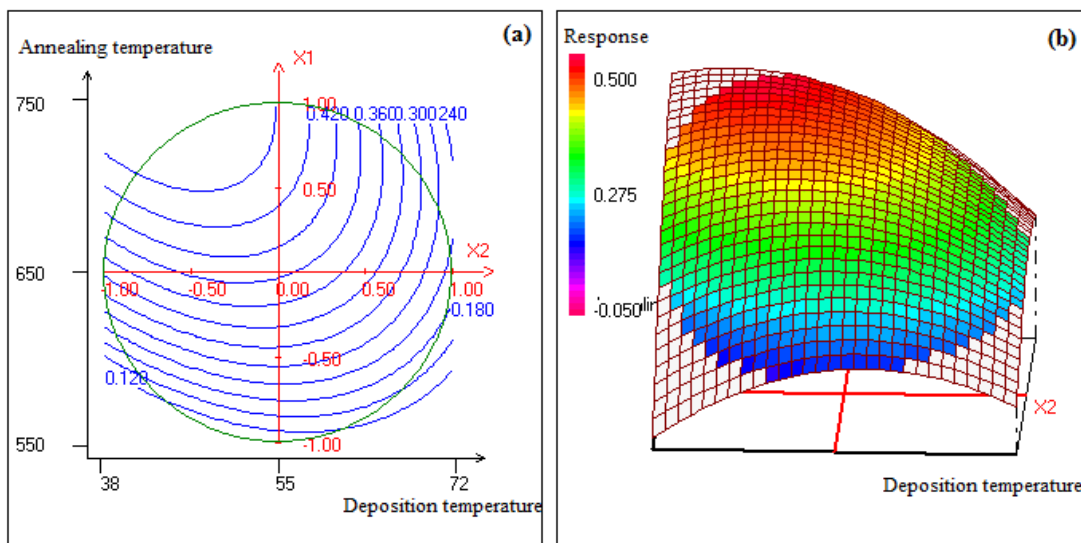


Fig. 3. (a) Contour plots of saturation magnetization (M_s) versus deposition temperature (°C) and annealing temperature (°C), (b) The corresponding three-dimensional plot.

The effects of interaction between deposition and annealing temperature on saturation magnetization were represented in **Fig.3**. As can be seen, the maximums of the saturation magnetization (M_s) of NiFe_2O_4 are obtained for annealing temperatures tend around $750\text{ }^\circ\text{C}$. In addition, to improve the response studied, it would be useful to increase the annealing temperature for deposition temperatures below $60\text{ }^\circ\text{C}$. Consequently, the optimal working condition that allows the formation of NiFe_2O_4 thin film with a maximum M_s (0.48 T) was found at: $T_R = 739\text{ }^\circ\text{C}$ and $T_d = 47\text{ }^\circ\text{C}$.

2.5. Characterization of the optimal condition of NiFe_2O_4 thin film

The structural properties of NiFe_2O_4 thin film prepared under optimal conditions determined from Doehler matrix, is investigated by X-ray diffraction. **Figure. 4a** shown the X-ray diffractogramme of NiFe_2O_4 thin film. The observed reflection peaks located at 30.13° , 35.50° , 44.47° , 57.19° , 74.93° were assigned to the (2 2 0), (3 1 1), (4 0 0), (5 1 1) and (5 3 3) planes respectively which correspond to the spinel ferrite NiFe_2O_4 with a cubic symmetry, and $Fd-3m$ space group. Whereas, peaks located at 43.59° , 50.86° and 74.68° were attributed to stainless steel (SS) substrate. The obtained pattern found to be in good agreement with the JCPDS files (Card No.10-325) which confirmed the formation of cubic NiFe_2O_4 phase.

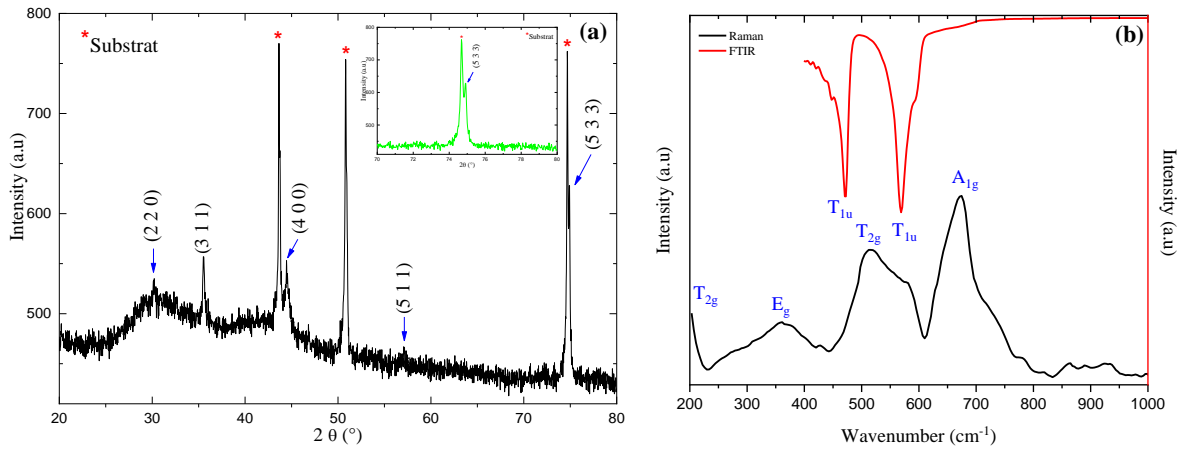


Fig. 4. (a) X-ray diffraction pattern and (b) Raman, FTIR spectra of NiFe_2O_4 thin film deposited at $T_R = 739\text{ }^\circ\text{C}$ and $T_d = 47\text{ }^\circ\text{C}$.

The average crystallite size (D), microstrain (ε) and dislocation density (δ) of the optimal condition of NiFe_2O_4 thin film were determined using the following relations:

$$D = \frac{k\lambda}{\beta \cos \theta} \quad (10)$$

$$\varepsilon = \frac{\beta}{4 \tan \theta} \quad (11)$$

$$\delta = \frac{1}{D^2} \quad (12)$$

Where:

k is the Scherrer constant, λ is the Cu(K α) radiation wavelength, β is the full width at half-maximum (FWHM) and θ is the diffraction Bragg angle.

The crystallite size (D), microstrain (ε) and dislocation density (δ) determined from the above formulas were found to be in the order of 38 nm, 0.40 and $6.92 \times 10^{14} \text{ m}^{-2}$ respectively. It is well known that the magnetic parameters for the complex oxides strongly depend on the average and distribution of crystallite size.

Raman and FTIR spectra of the thin film is presented in **Fig. 4b**. All these peaks and bands can be attributed to NiFe₂O₄. The peaks at 202 and 516 cm⁻¹ are assigned to T_{2g} modes, and those at 359 and 673 cm⁻¹ are assigned to E_g and A_{1g} modes respectively. The bands located at 470 and 568 cm⁻¹ in FTIR spectra are assigned to Nickel ferrite (NiFe₂O₄) sample. The band at 359 cm⁻¹ exhibits the stretching vibrations due to Ni-O and the band at 568 cm⁻¹ correspond to stretching vibrations of Fe-O. The spectroscopy analysis confirms the formation of spinel structure of NiFe₂O₄ found in structural study.

The energy dispersive X-ray spectrometry (EDX) was used to determine the elemental composition of the obtained film. The EDX spectra shows (**Fig.5**) that the Fe/Ni atomic percentage was detected by a ratio of $R_{\text{Fe/Ni}}=2$ which confirms the formation of stoichiometric ferrite nickel thin film with absence of any impurity. As can be seen, the Ni, Fe and O signals are higher than the C signal. This large amount of C into the film is derived from the double-sided carbon tape of SEM measurements confirmed by element mapping images. SEM images (**Fig.5**) demonstrate that the elaborated film has a good coverage with flower-like structure, which is formed by the assembly of flower petal layers. The average crystallite sizes deduced from image treatments for the film are in the range of 52 and 118 nm. However, the homogeneous distribution of Ni, Fe and O was observed also in the element mapping images.

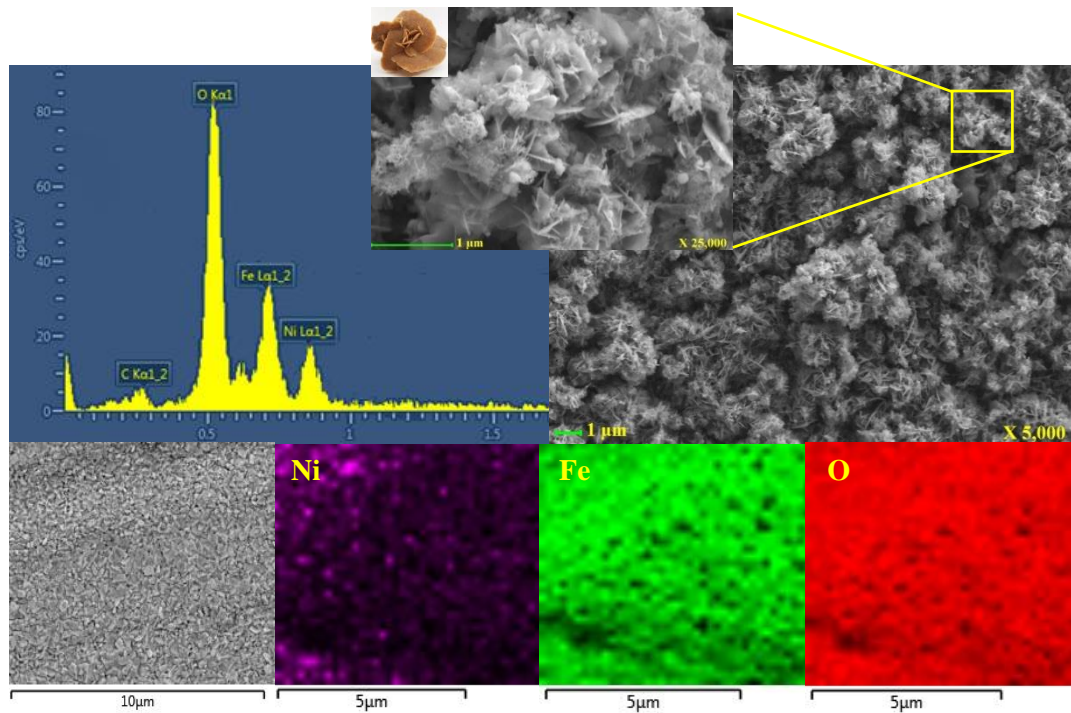


Fig. 5. EDX spectra, SEM image with corresponding elemental mapping images of NiFe₂O₄ thin film deposited at $T_R = 739\text{ }^\circ\text{C}$ and $T_d = 47\text{ }^\circ\text{C}$.

In order to correlate the result found in Doehlert methodology to magnetic properties, hysteresis loops (M–H curve) for NiFe₂O₄ thin film prepared under optimal conditions was investigated. The Magnetic hysteresis loops measured in and out-of-plane in the field range of $\pm 15\text{ kA/m}$ at room temperature are shown in **Fig.6**.

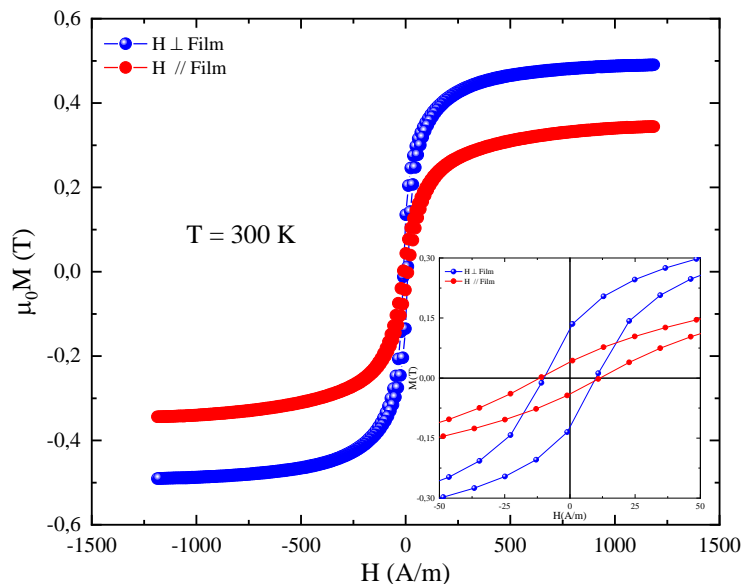


Fig. 6. M-H hysteresis loops of NiFe₂O₄ thin film deposited at $T_R = 739\text{ }^\circ\text{C}$ and $T_d = 47\text{ }^\circ\text{C}$.

The in-plane measurement of the NiFe₂O₄ thin film has shown a saturation magnetization (M_s) equal to 0.49 T with a coercivity (H_c) of 12.02 kA/m. The magnetocrystalline anisotropy energy [32] was calculated by the following equation:

$$K_u = \frac{H_c M_s}{2}$$

The value of the magnetocrystalline anisotropy energy is equal to 2.95 J/m³. The sample was rotated perpendicular from the initial position and the hysteresis loop resulting from the out-plane measurement was recorded. The M_s and H_c values significantly increased to 0.34 T and 12.04 kA/m, respectively. However, this significant difference between in-plane and out-of-plane saturation magnetization is due to effect of magnetic anisotropy. The NiFe₂O₄ thin film exhibits a soft ferrimagnetic behavior at room temperature with a large saturation magnetization.

The electrochemical properties of the NiFe₂O₄ were evaluated by CV, EIS, and Tafel polarization measurements within a three-electrode cell in 1 M NaOH aqueous electrolyte.

The CV curves measured at a scan rate of 100 mVs⁻¹ are represented in **Fig.7a**. Apparently, the CV curve shows a semi-rectangular shape in the potential window of -0.5 to 0.5 V without any oxidation/reduction peak. The semi-rectangular shape observed in CV curves in the negative and positive potential, indicate the double-layer capacitance (EDLC) of NiFe₂O₄ electrode.

To confirm the double layer capacitance of the NiFe₂O₄ electrode the EIS measurement has been study. The Nyquist plot and the equivalent circuit are shown in **Fig.7b**. Nyquist plot consist two parts, a semicircle in the high-frequency region and a straight line in the low-frequency region. The large radius of the semicircle is assigned to the charge transfer resistance of the electrode and the vertical line is attributed to the dominant capacitive behavior of the electric double layer formed at the electrode/ electrolyte interface. The values of R_s, R_{ct}, C and W were estimated qualitatively from the fittings of experimental impedance spectra which are equal to 29.4 Ω, 43.5 Ω, 0.43μF and 0.27 Ω.s⁻⁵ respectively.

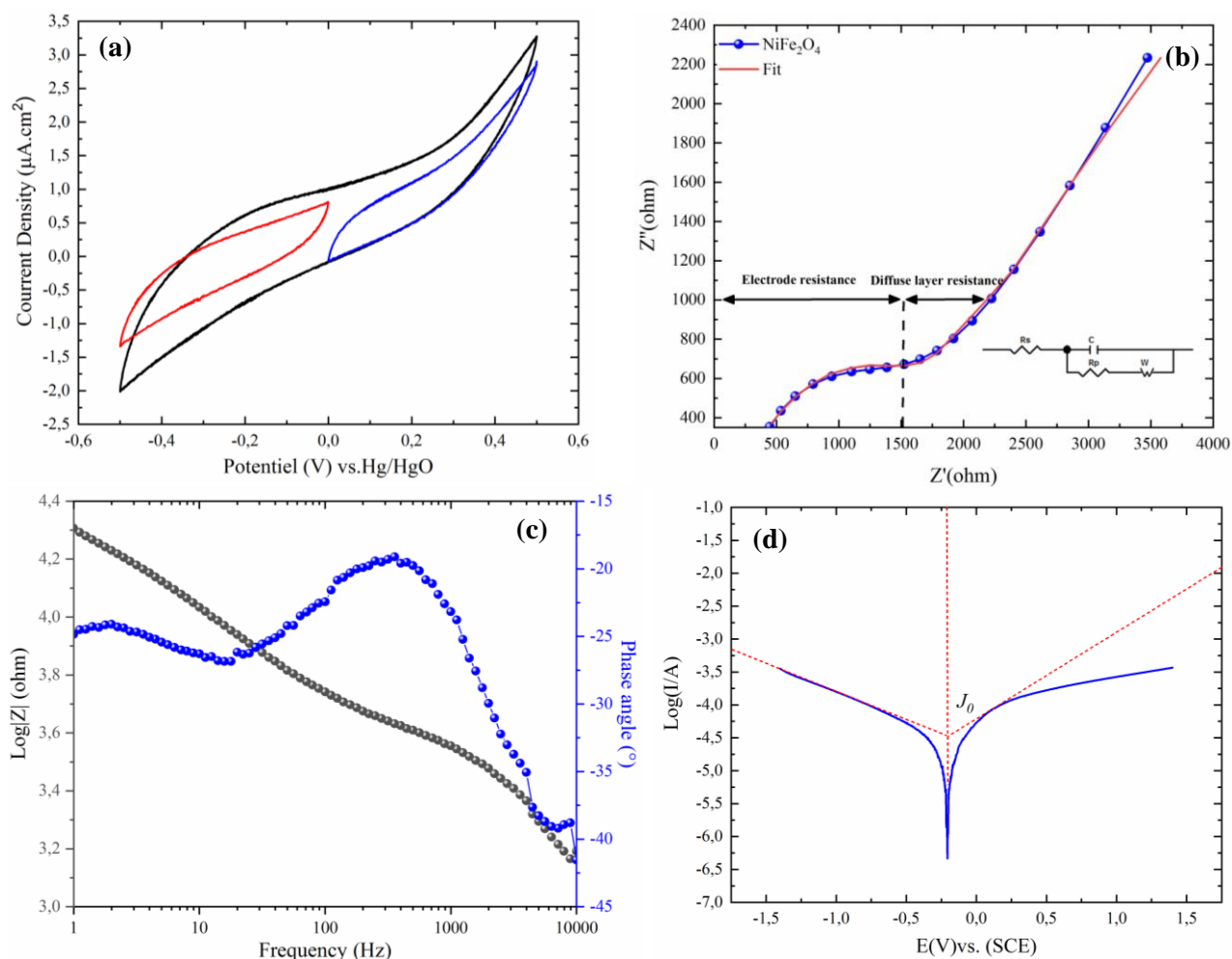


Fig.7. (a) The cyclic voltammograms, (b) Nyquist plot with equivalent circuit, (c) Bode plots and (d) Tafel plot of NiFe₂O₄ thin film deposited at $T_R = 739\text{ }^\circ\text{C}$ and $T_d = 47\text{ }^\circ\text{C}$.

The Bode plots (Frequency (Hz) vs. Phase angle ($^\circ$) and $\text{Log}|Z|$) of the NiFe₂O₄ nanoflowers are presented in **Fig.6c**. At low frequency when the phase angle approaches to 90° that indicates the ideal capacitive behavior of the electrode, and when the phase angle is close to 0° that indicates the pure resistance behavior of the material. The phase angle of the prepared NiFe₂O₄ thin film, is equal to 19° at low frequency which corresponds to resistance contribution of the electrode. The results of Bode plots confirm the resistance behavior of electrode found in EIS measurement.

The potentiodynamic polarization test was performed just a few minutes after Impedance measurements to determine the corrosion rates of the electrode. The Tafel polarization curve of NiFe₂O₄ electrode is shown in **Fig.7d**. The calculation of corrosion potential (E_{corr}) and corrosion current density (I_{corr}) based on the Tafel slope method are equal to -0.2 V and $-14.07\text{ }\mu\text{A}$, respectively.

Conclusion

Rechtschaffner design has been adopted to determine the most influential parameters on saturation magnetization (M_s). In fact, Rechtschaffner design demonstrated that the deposition and annealing temperature are the most influential parameters on M_s . To elaborate the NiFe_2O_4 thin film, the optimal condition has been predicted by Doehlert matrix. The spinel structure of the obtained film has been investigated by DRX, Raman and FTIR. The nanoflower morphology of the NiFe_2O_4 film has been confirmed by SEM. To correlate the result found in Doehlert methodology to magnetic properties, hysteresis loops ($M-H$ curve) for NiFe_2O_4 thin film prepared under optimal conditions has been examined. Electrochemical properties of the NiFe_2O_4 film has been tested with three electrodes system in 1 M NaOH electrolyte at room temperature. We believe that the elaborate film can be an excellent electrode for EDLC devices.

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